RTGN141AP

TRANSISTOR WITH RESISTOR FOR SWITHING APPLICATION SILICON NPN EPITAXIAL TYPE

DISCRIPTION

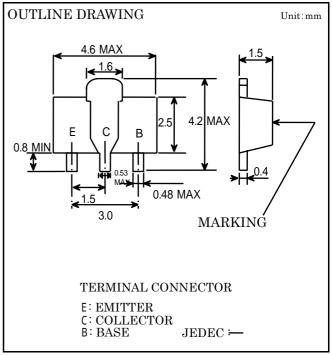
RTGN141AP is a one chip transistor with built-in bias transistor.

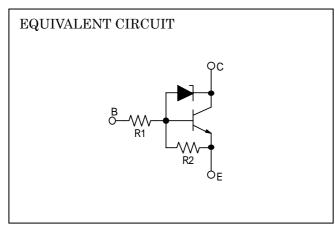
FEATURE

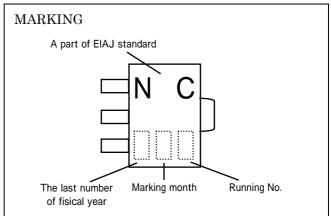
Built-in bias resistor (R1= $10k\Omega$,R2= $10k\Omega$) High collector current IC=1ABuilt-in zener diode between collector and base

APPLICATION

Motor driver circuit







MAXIMUM RATING (Ta=25)

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SYMBOL	PARAMETER	RATING	UNIT			
$V_{\rm CBO}$	Collector to Base voltage	60±10	V			
$V_{\rm EBO}$	Emitter to Base voltage	10	V			
$V_{\rm CEO}$	Collector to Emitter voltage	60±10	V			
I_{C}	Collector current (DC)	1	A			
I_{CM}	Collector current (pulse)	2	A			
$P_{\rm C}$	Collector dissipation	500	mW			
$T_{\rm j}$	Junction temperature	+ 150				
$\mathrm{T}_{\mathrm{stg}}$	Storage temperature	-55 ~ + 150				

SMALL-SIGNAL TRANSISTOR

RTGN141AP

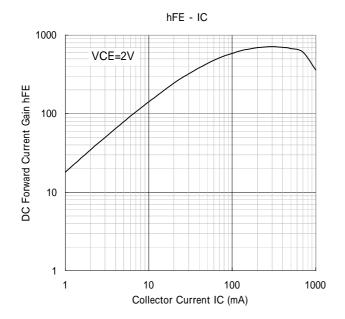
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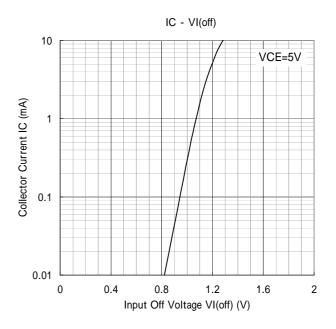
ELECTRICAL CHARACTERISTICS(Ta=25)

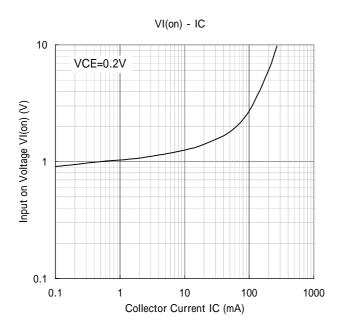
Symbol	Parameter	Test conditions	Limits			Unit
Symbol			Min	Тур	Max	Omi
I _{CBO}	Collector cut off current	V _{CB} =40V , IE=0			0.1	uA
V_{OL}	Output voltage	VI=5V , I _C =100mA			0.2	V
V_{IL}	Input voltage (OFF)	V _{CE} =5V , I _C =100 μ A	0.3			V
hFE1	DC forward current gain	V _{CE} =2V , I _C =0.1A	200			
hFE2	DC forward current gain	$V_{CE}=2V$, $I_{C}=0.5A$	300			
hFE3	DC forward current gain	$V_{CE}=2V$, $I_{C}=1A$	200			
R ₁	Input resistor		7	10	13	K
R ₂	Emitter – Base resistor		7	10	13	K

<SMALL-SIGNAL TRANSISTOR> RTGN141AP

TRANSISTOR WITH RESISTOR FOR SWITHING APPLICATION SILICON NPN EPITAXIAL TYPE









Marketing division, Marketing planning department 6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

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